SDLS189

D2420, APRIL 1979-REVISED MARCH 1988

- SN74LS64X-1 Versions Rated at I_{OL} of 48 mA
- Bi-directional Bus Transceivers in High-Density 20-Pin Packages
- Hysteresis at Bus Inputs Improves Noise Margins
- · Choice of True or Inverting Logic
- Choice of 3-State or Open-Collector Outputs

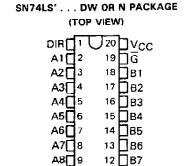
DEVICE	OUTPUT	LOGIC
'LS640	3-State	Inverting
'LS641	Open-Collector	True
'L\$642	Open-Collector	Inverting
'LS644	Open-Collector	True and inverting
'LS645	3-State	True

description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus depending upon the level at the direction control (DIR) input. The enable input (\overline{G}) can be used to disable the device so the buses are effectively isolated.

The -1 versions of the SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are identical to the standard versions except that the recommended maximum IQL is increased to 48 milliamperes. There are no -1 versions of the SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645.

The SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645 are characterized for operation over the full military temperature range of $-55\,^{\circ}\text{C}$ to $125\,^{\circ}\text{C}$. The SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are characterized for operation from 0 $^{\circ}\text{C}$ to $70\,^{\circ}\text{C}$.

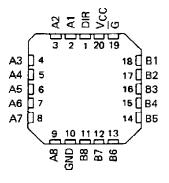


SN54LS' . . . J PACKAGE

SN54LS' . . . FK PACKAGE (TOP VIEW)

11 B8

GND□

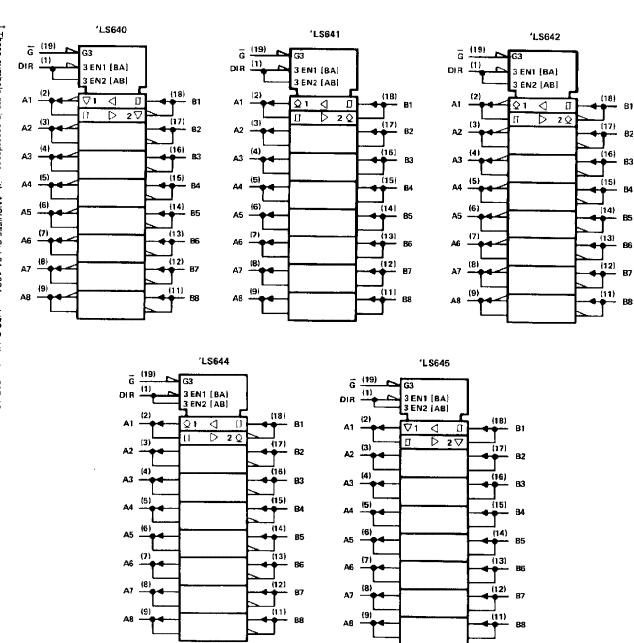


FUNCTION TABLE

CONTROL			OPERATION	
INPUTS		'LS640	'LS641	'LS644
G	DIR	'L\$642	'LS645	L3644
L	L	B data to A bus	B data to A bus	B data to A bus
L	Н	A data to B bus	A data to B bus	A data to B bus
н	Х	Isolation	Isolation	Isolation

H = high level, L= low level, X = irrelevant

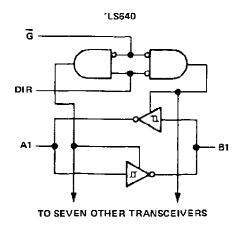
logic symbols†

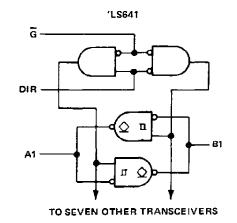


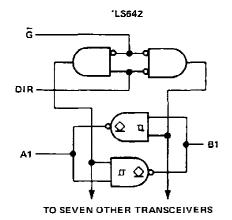


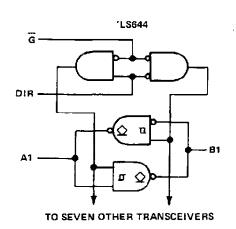


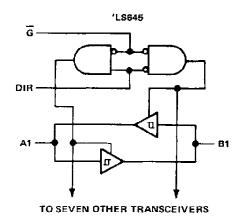
logic diagrams (positive logic)











NOTE 1: Voltage values are with respect to network ground terminal.

recommended operating conditions

	PARAMETER]	SN54LS640 SN54LS645					UNIT
		MIN	MIN NOM N		MIN	NOM	MAX	
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
v_{IH}	High-Ivel input voltage	2			2			V
VIL	Low-level input voltage			0.5			0.6	V
IOH	High-level autput current			- 12			- 15	mA
lOL	Low-level output current			12			24	
						_	48 [†]	mΑ
TA	Operating free-air temperature	- 55		125	0		70	С

[†]The 48-mA limit applies for the SN74LS640-1 and SN74LS645-1 only.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS‡			1	N54LS6 N54LS6		s	UNIT		
					MIN	TYP§	MAX	MIN	TYP§	MAX	1
ViK		V _{CC} = MIN,	$i_1 = -18 \text{ mA}$	"			- 1.5			- 1.5	V
	teresis - VT_)	V _{CC} = MIN,		A or B input	0.1	0.4		0.2	0.4		V
Voн		V _{CC} = MIN.	V _{IH} = 2 V,	10H = - 3 mA	2.4	3.4		2.4	3.4		
•ОН		V _{IL} = MAX		IOH = MAX	2			2			1
	Vac = MIN	V _{CC} = MIN,	V = 2 V	IOL = 12 mA		0.25	0.4		0.25	0.4	
VOL	VIL = MAX	· i m = - /	IOL = 24 mA	1				0.35	0.5	V	
<u></u> .		AIT MWY		I _{OL} = 48 mA#					0.4	0.5	
lozн		VCC = MAX,		V _O = 2.7 V			20			20	μA
loz L		VCC = MAX,	Ĝaτ2V,	V _O = 0.4 V		•	- 0.4			- 0.4	mΑ
fj	A or B	V _{CC} = MAX		V ₁ = 5.5 V			0.1			0.1	mΑ
' I	DIR or $\overline{\mathbb{G}}$	* CC WAX		V ₁ = 7 V			0.1			0.1	I III A
ΉΗ		VCC = MAX.	V _{IH} = 2.7 V				20			20	μА
ΙιΓ		V _{CC} = MAX,	V _{IL} = 0.4 V		Ī		- 0.4			- 0.4	mA
los*		V _{CC} = MAX		·	~ 40		- 225	- 40		- 225	mΑ
	Outputs high					48	70		48	70	
ICC	Outputs low	VCC = MAX.	Outputs open			62	90		62	90	mA
	Outputs at Hi-Z					64	95		64	95	1

For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

^{*}The 48-mA condition applies for the SN74LS640-1 and SN74LS645-1 only.



 $^{^{5}}$ All typical values are at V_{CC} = 5 V, T_{A} = 25 °C.

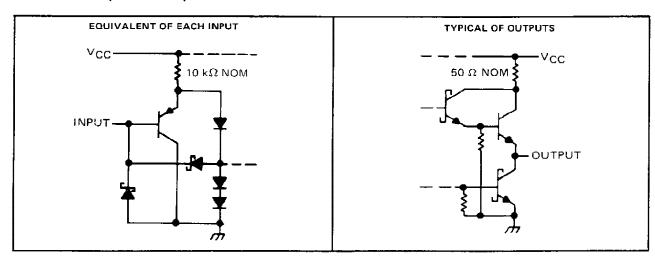
Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

switching characteristics, VCC = 5 V, $TA = 25 ^{\circ}C$

	PARAMETER	FROM	то	TEST	'LS64	10, 'LS6	40-1	'L\$64	5, 'LS6	45-1	UNIT	
	PANAMETER		(OUTPUT)	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
*m	Propagation delay time,	А	В			6	10		8	15	ns	
^t PLH	low-to-high-level output	В	A			6	10	-	8	15	ns	
****	Propagation delay time,	Α	8	C: 45 -5		8	15		11	15		
^t PHL	high-to-low-level output	8	Α	$C_L = 45 \text{ pF},$ $R_L = 667 \Omega,$		8	15		11	15	ns	
*	Output enable time to	Ğ	Α			31	40		31	40		
^t PZL	low level	ত্ত	В	See Note 2		31	40		31	40	ns	
•==::	Output enable time to	G	Α			23	40		26	40		
₹PZH	high level	G	В			23	40		26	40	ns	
*-	Output disable time	Ğ	А	0 5 5		15	25		15	25		
tPLZ	from low level	G	В	$C_L = 5 \text{ pF},$ $R_L = 667 \Omega,$		15	25		16	25	ns	
*=	Output disable time	Ğ	А			15	25		15	25		
tpHZ	from high level	G	В	See Note 2		15	25		15	25	ns	

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

schematics of inputs and outputs



TYPICAL CHARACTERISTICS

SN54LS' INVERTING OUTPUT VOLTAGE

FIGURE 1

\$N54LS' NONINVERTING OUTPUT VOLTAGE

TA = 125°C

TA 25°C

TA = -55°C

TA = -55°C

TA = -55°C

TA = -55°C

FIGURE 3

SN74LS' INVERTING OUTPUT VOLTAGE

TA = 70°C

TA = 25°C

TA = 0°C

TA = 0°C

V_I-Input Voltage-V
FIGURE 2

1

0

0.5

\$N74LS' NONINVERTING OUTPUT VOLTAGE

INPUT VOLTAGE

TA = 70°C

TA = 25°C

TA = 0°C

TA = 0°C

VI-Input Voltage-V

FIGURE 4



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)	7V
Input voltage: All inputs and I/O ports	7V
Operating free-air temperature range: SN54LS641, SN54LS642, SN54LS644	125° C
SN74LS641, SN74LS642, SN74LS644	o 70° C
Storage temperature range	150° C

NOTE 1: Voltage values are with respect to network ground terminal,

recommended operating conditions

PARAMETER		SN54LS SN54LS SN54LS	642	s	N74LS6 N74LS6 N74LS6	342	UNIT
	MIN	NOM	MAX	MIN	NOM	MAX]
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	٧
V _I µ High-level input voltage	2			2			V
V _{IL} Low-level input voltage			0.5			0.6	V
VOH High-level output voltage			5.5			5.5	V
lor Low-level output current			12			24	
IOL Low-level output current	<u> </u>			48 §			mA
TA Operating free-air temperature	- 55		125	0		70	°C

[§]The 48 mA limit applies for the SN74LS641-1, \$N74LS642-1, and SN74LS644-1 only.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CO	SN54LS641 SN54LS642 SN54LS644			S S	UNIT			
				MIN	TYP‡	MAX	MIN	TYP#	MAX	
VΙΚ		V _{CC} = MIN,	I _I = - 18 mA	1		- 1.5			- 1.5	V
Hysteres (V _{T+} – V _T		V _{CC} = MIN,	A or B input	0.1	0.4		0.2	0.4		V
IOH		V _{CC} = MIN, V _{IL} = MAX,	V _{IH} = 2 V, V _{OH} = 5.5 V			0.1			0.1	mΑ
		V _{CC} = MIN,	IOL = 12 mA		0.25	0.4		0.25	0.4	
VOL		V _{1H} ≈ 2 V,	I _{OL} = 24 mA					0.35	0.5	V
		V _{IL} = MAX	10L = 48 mA∜	-				0.4	0.5	
1.	A or B)/ 044 Y	V _I = 5.5 V		9.11	Q. 1			0.1	
i į	DIR or G	V _{CC} = MAX	V ₁ = 7 V			0.1			0.1	mA.
1 _{1H}		V _{CC} = MAX,	V _I = 2.7 V			20			20	μА
ΊL		V _{CC} = MAX,	V! = 0.4 V			- 0.4			- 0.4 [′]	mΑ
	Outputs high				48	70		48	70	
1cc	Outputs low	V _{CC} = MAX,	Outputs open		62	90		62	90	mA
	Outputs at Hi-Z				64	95		64	95	

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

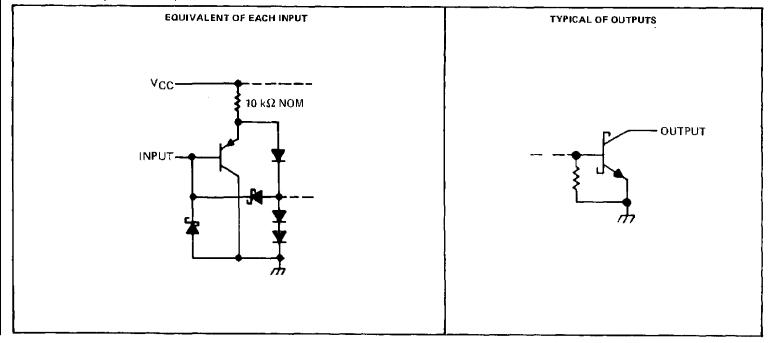
[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C. §The 48 mA condition applies for the SN74LS641-1, SN74LS642-1, and SN74LS644-1 only.

switching characteristics at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER	PARAMETER FROM TO TEST ROMOTIONS 'LS641, 'LS641-1		TEST CONDITIONS				641-1	'LS64	12, 'LSI	542-1	'LS644, 'LS644-1			
· Allawe i eli	(INPUT)	(OUTPUT)	UT) TEST CONDITIONS IN	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
Propagation delay time,	A	В			17	25		19	25		17	25		
^t PLH low-to-high-level output	В	Α	0 - 45 - 5		17	25		19	25		19	25	ns	
Propagation delay time,	А	8	- C _L = 45 pF,		16	25		14	25	<u> </u>	14	25		
TPHL high-to-low-level output	В	А	5 . 607.6		16	25		14	25	ļ	16	25	ns	
Output disable time	Ĝ, DIR	А	R _L = 667 Ω,		23	40		26	40	ļ ——	26	40		
tpLH from low level	Ğ, DIR	8	1		25	40		28	40		25	40	ns	
Output enable time	Ğ, DIR	А	See Note 2		34	50		43	60		43	60		
tpHL from high levet	G, DIR	В	1		37	50		39	60		37	50	ns	

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

schematics of inputs and outputs



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